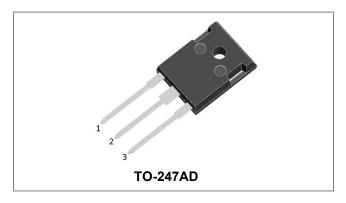


30CPQ050 30CPQ060

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30CPQ050/30CPQ060 SCHOTTKY RECTIFIER



Circuit Diagram



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	50(30CPQ050) 60(30CPQ060)	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=112°C, rectangular wave form	15(Per Leg) 30(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _C = 25 °C	315	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 15A, Pulse, TJ = 25 °C @ 30A, Pulse, TJ = 25 °C	0.55 0.69	0.60 0.80	V
	VF2	@ 15A, Pulse, T」 = 125 °C @ 30A, Pulse, T」 = 125 °C	0.50 0.63	0.56 0.70	V
Reverse Current (Per Leg)*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.04	0.8	mA
	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	22	100	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	766	1000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^*\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

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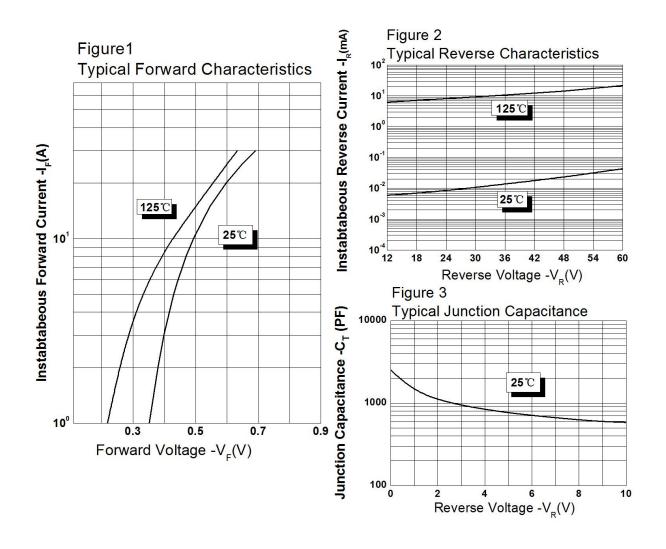
30CPQ050 30CPQ060

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.2(Peg Leg) 1.10(Peg Device)	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.24	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

Ratings and Characteristics Curves



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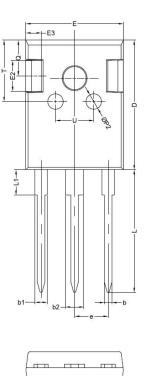
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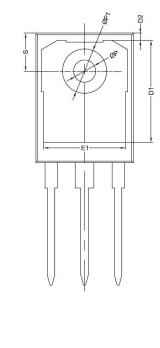
30CPQ050 30CPQ060

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Mechanical Dimensions TO-247AD

A1-





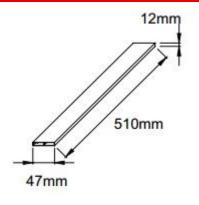
CYMPOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
А	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
D2 E	15.45	15.80	16.00		
E1		13.30			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
Q		5.80			
Q S T	6.05	6.15	6.25		
Т		10.00			
U		6.20			

Ordering Information:

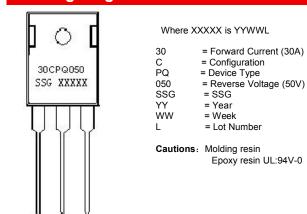
Device	Package	Shipping	
30CPQ050(060)	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification



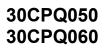
Marking Diagram



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